

# VOICE/MELODY/LCD CONTROLLER (ViewTalk TM Series)

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#### 1. GENERAL DESCRIPTION

The W536XXXT, a member of  $ViewTalk^{TM}$  family, is a high-performance 4-bit micro-controller (uC) with built-in speech unit, melody unit and 64seg \* 32 com LCD driver unit which includes internal regulator, pump circuit and dedicated two pages LCD RAM. The 4-bit uC core contains dual clock source, 4-bit ALU, two 8-bit timers, one 14 bits divider, maximum 24 pads for input or output, 8 interrupt sources and 8-level nesting for subroutine/interrupt applications. Speech unit, integrated as a single chip with maximum 128 seconds (based on 6.4K sample rate with 5 bits MDPCM), is capable of expanding to 512 seconds speech addressed by external memory W55XXX with serial bus interface.

It can be implemented with Winbond Power Speech using MDPCM algorithm. Melody unit provides dual tone output and can store up to 1k notes. Power reduction mode is also built in to minimize power dissipation. It is ideal for games, educational toys, remote controllers, watches, clocks and other application products which incorporate both LCD display and speech.

BODY	W536030T	W536060T	W536090T	W536120T
Voice	30 sec	60 sec	90 sec	120 sec
I/O pad	4I/O, 4I	4I/O, 8I	8I/O, 8I, 8O	8I/O, 8I, 8O
I/O pau	(RA/RD)	(RA/RC/RD)	(RA/RB/RC/RD/RE/RF)	(RA/RB/RC/RD/RE/RF)
WDT disable/Enable	Y	Y	Y	V
(Mask Option)		Y	Y	Y
Sub-clock				
RC/XTAL mode	Y	Y	Υ	Y
(Mask Option)				
RD port shared as serial bus				
	Y(1)	Y(1)	N	N (2)
(Mask Option)				
Tri-state serial bus	Y	Y	Y	Y
(Mask Option) (3)		1	1	1
Cascaded Voice ROM through serial bus (2)	Y(1)	Y(1)	N	Y

- (1). Share 3 pads of RD port (RD1/CLK, RD2/DATA and RD3/ADDR)
- (2). Dedicate serial bus 3 pads (CLK, DATA and ADDR) to interface with W55XXX. Cascaded Voice ROM can help user to expand voice up to 512 sec by W55XXX chip.
- (3). Tri-state serial bus mask option can float serial bus while voice playing is no active. Let this mask option is disabled to get minimum power consumption in general.



### 2. FEATURES

- Operating voltage: 2.4 volt ~ 5.5 volt
- Watch dog disabled/enabled by mask option
- Dual clock operating system
  - Main clock with Ring/Crystal (400 KHz to 4 MHz)
  - Sub-clock with 32.768 KHz RC/Crystal by mask option
- Memory
  - Program ROM (P-ROM): 64K × 20 (ROM Bank0, 1, 2, 3, 4, 5, 6)
  - Data RAM (W-RAM): 1.4K × 4 bit

(RAM Bank 0 is 896 nibbles from 0:  $000\sim0.37F$  and 0:  $380\sim0.3FF$  are mapped to special register.

RAM Bank F is 512 nibbles from F: 200~F: 3FF either data RAM or dedicated to script kernel)

- LCD RAM (L-RAM): 512 × 4 bit × 2 pages (RAM Bank1, 2 from 200~3FF)
- Maximum 24 input/output pads
  - Ports for input only: 8 pads (RC, RD port; RD1~3 can share as serial bus for external memory W55XXX interface @W536030T/060T)
  - Ports for output only: 8 pads (RE & RF port; W536090T/120T available only)
  - Ports for Input/output: 8 pads (RA and RB port; RB port is available for W536090T /W536120T only)
- Power-down mode
  - Hold mode (except for 32KHz oscillator)
  - Stop mode (including 32KHz oscillator and release by RD or RC port)
- Eight types of interrupts
  - Five internal interrupts (Divider, Timer 0, Timer 1, Speech, Melody)
  - Three external interrupts (Port RC, RD, RA)
- One built-in 14-bit clock frequency divider circuit
- Two built-in 8-bit programmable countdown timers
  - Timer 0: one of two clock sources (FOSC/4 or FOSC/1024) can be selected
  - Timer 1: built-in auto-reload function includes internal timer, external event counter from RC.0

- 3 -

- Built-in 18/14-bit watchdog timer for system reset.
- · Powerful instruction sets
- 8-level subroutine (including interrupt) nesting
- · LCD driver unit capability
  - VLCD higher than (V<sub>DD</sub> -0.5V)
  - Built-in voltage regulator to V2 pad
  - 64 seg × 32 com



- 1/32 or 1/16 duty, 1/5 or 1/4 bias, internal pump circuit option by special register
- COM24~ 31 and SEG40~63 can be shared as general input/output by special register
- Either uC ROM or voice ROM used as LCD picture

#### Speech function

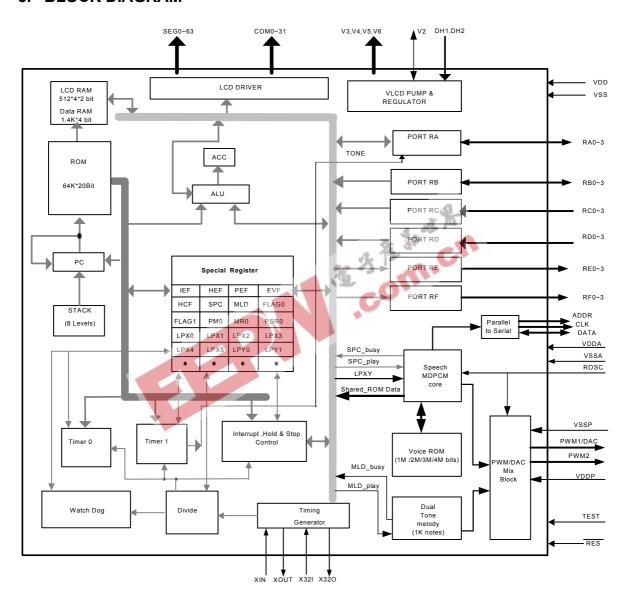
- Provided 1M / 2M/ 3M/ 4M bits Voice ROM for W536030T/060T/090T/120T based on 5 bits MDPCM algorithm
- Voice ROM (V-ROM) available for uC data or LCD picture data.
- Maximum 8\*256 Label/Interrupt vector (voice section number) available
- Provide two types of speech busy flag to either each GO or each trigger
- Maximum up to 16M bits speech address capability interface with external memory W55XXX through serial bus.

#### Melody function

- Provide 1K notes (22bits/note) dedicated melody ROM
   Provide two firsts (2.2bits/note).
- Provide two types of melody busy flag to uC either each note or each song
- Provide 6 kinds of beat, 16 kinds of tempo, and pitch range from G3# to C7
- Tremolo, triple frequency and 3 kinds of percussion available
- Maximum 31 songs available
- Can mix speech with melody
- Multi-engine controller
- Direct driving speaker/buzzer or DAC output
- Chip On Board available



## 3. BLOCK DIAGRAM





# 4. PAD DESCRIPTION

SYMBOL	I/O	FUNCTION
XIN/RXIN	I	Input pad for main clock oscillator. It can be connected to crystal when crystal mode is selected (SCR0.2 = 1), otherwise connect a resistor to $V_{DD}$ to generate main system clock while Ring mode is selected (SCR0.2 = 0 and default). Oscillator can be enabled or stopped by set SCR0.1 to 1 or clear to 0 separately. External capacitor connects to start oscillation and get more accurate clock when crystal mode
XOUT	0	Output pad for oscillator which is connected to another crystal pad when in crystal mode. External capacitor connects to start oscillation when in crystal mode.
X32I/RSUB1	I	32.768 KHz crystal input pad or external resistor node 1 <b>by mask option</b> . External 15~20pF capacitor connects to start oscillation and get more accurate clock when in crystal mode.
X32O/RSUB2	0	32.768 KHz crystal output pad or external resistor node 2 <b>by mask option.</b> External 15~20pF capacitor connects to start oscillation when in crystal mode.
RA0 ~ RA3/TONE (8)	I/O	General Input/Output port specified by PM1 register. If output mode is selected, PM0 register bit 0 can be used to specify CMOS/NMOS driving capability option. Initial state is input mode. RA3 may be uses as TONE if bit 0 of MR0 special register is set to logic 1. An interrupt source.
RB0 ~ RB3 (8)	1/0	General Input/Output port specified by PM2 register. If output mode is selected, PM0 register bit 1 can be used to specify CMOS/NMOS driving capability option. Initial state is input mode (W536090T /W536120T only.)
RC0 ~ RC3	I	4-bit schmitter input with internal pull high option specified by PM3 register bit 2. Each pad has an independent interrupt capability specified by PEFL special register. Interrupt and STOP mode wake up source. RC0 is also the external event counter source of Timer1. (W536060T/090T/120T only.)
RD0 RD1/CLK RD2/DATA RD3/ADDR (4)	I	4-bit schmitter input port with internal pull high option specified by PM3 register bit 3. Each pad has an independent interrupt capability specified by PEFH special register. Interrupt and STOP mode wake up source. RD1~3 will be shared as the external memory W55XXX interface pads while RD port shared as serial bus mask option is enabled @W536030T/060T.
RE0~RE3 (8)	0	Output port only. PM3 register bit 0 can be used to specify CMOS/NMOS driving capability option. (W536090T/120T only)
RF0~RF3 (8)	0	Output port only. PM3 register bit 1 can be used to specify CMOS/NMOS driving capability option. (W536090T/120T only)
ii	1	System reset pad, active low with internal pull-high resistor.



#### PAD Description, continued

SYMBOL	I/O	FUNCTION
TEST	I	Test pad. Active high with internal pull low resistor.
ROSC	ı	Connect resistor to $V_{\text{DD}}$ pad to generate speech or melody playing clock source.
PWM1/DAC	0	While speech or melody is active, PWM1/DAC is speaker direct driving output or DAC output controlled by voice output file.
PWM2	0	While speech or melody is active, PWM2 is another speaker direct driving output.
ADDR (5)	0	External serial memory address write clock for voice extension (W536120T only). The "Tri-sate serial bus" <b>mask option</b> can use trisate WRP pad while external voice ROM is not available. Default that mask option is disabled and fixes WRP pad state while external voice is not enabled to get chip low power consumption.
CLK (5)	0	External serial memory address read clock for voice extension. (W536120T only). The pad state is same as WRP pad depended on "Tri-sate serial bus" mask option.
DATA (5)	I/O	External serial memory data in/out for voice extension (W536120T only). The pad state is same as WRP pad depended on "Tri-sate serial bus" mask option.
SEG0-SEG39	0	Dedicated LCD segment output pads.
SEG40/PORTN.0     SEG43/PORTN.3	0/0	LCD segment output pads, and can be shared as general output by register LCDM3 bit 1. Default function is segment pad.
SEG44/PORTM.0   SEG47/PORTM.3	O/I	LCD segment output pads, and can be shared as general input by register LCDM3 bit 0. Default function is segment pad and PM5.1=0 to inhibit LCD waveform abnormal.
SEG48/PORTL.0   SEG51/PORTL.3	O/O	LCD segment output pads, and can be shared as general output by register LCDM2 bit 3. Default function is segment pad.
SEG52/PORTK.0   SEG55/PORTK.3	O/I	LCD segment output pads, and can be shared as general input by register LCDM2 bit 2. Default function is segment pad and PM5.0 = 0 to inhibit LCD waveform abnormal.
SEG56/PORTJ.0   SEG59/PORTJ.3	O/IO	LCD segment output pads, and can be shared as general input/output by register LCDM2 bit 1. PM4 register is used to select input or output while shared I/O function is active. Default function is segment pad and PM4.3 = 0 to inhibit LCD waveform abnormal.
SEG60/PORTI.0   SEG63/PORTI.3	O/IO	LCD segment output pads, and can be shared as general input/output by register LCDM2 bit 0. PM4 register is used to select input or output while shared I/O function is active. Default function is segment pad and PM4.2 = 0 to inhibit LCD waveform abnormal.



#### PAD Description, continued

SYMBOL	I/O	FUNCTION
COM0-COM15	0	LCD common signal output pads either 1/32 duty or 1/16 duty. The LCD frame rate is controlled by LCDM1 register, and default value LCDM1 = 0111b with 64Hz frame rate.
COM16-COM23	0	LCD common signal output pads while 1/32 duty is active. The LCD frame rate is controlled by LCDM1 register, and default value LCDM1 = 0111b with 64Hz frame rate.
COM24/PORTP.0   COM27/PORTP.3	0/0	LCD common signal output pads, or shared as general output by register LCDM3.2 when in 1/16 duty mode. Default function is common function.
COM28/PORTO.0   COM31/PORTO.3	O/I	LCD common signal output pads, or shared as general input by register LCDM3.2 when in 1/16 duty mode. Default function is common function and PM5.2 = 0 to inhibit LCD waveform abnormal.
DH1, DH2 (6)	0	Connection terminal for voltage double capacitor with 0.1uF. The DH2 connects to capacitor positive node and DH1 negative node if polar capacitor is used.
V3 ~ V6 (6)	0	LCD COM/SEG output driving voltage. Need an external 0.1uF capacitor to every pad terminal.
V2 (6)	I/O	Voltage regulator output pad. An external capacitor is a must. Output level can be controlled from 0~Fh by LCDM4 register. If internal pump is enabled (LCDM3.3 = 0 and default value), LCD operating voltage (VLCD) will be 4*V2 or 5*V2 depending on 1/4 bias or 1/5 bias. A limitation should be noted that VLCD must be higher than ( $V_{DD}$ -0.5v) to avoid chip leakage current. While external reference voltage is selected (LCDM3.3 = 1), V2 pad input voltage can not be over 1.5 Volt to inhibit chip damage.
$V_{SSP}$		Power ground for PWM or DAC playing output.
V <sub>SSA</sub> (7)	I	Power ground. (For w536090/120T only)
V <sub>SS</sub>	I	Power ground
$V_{DDP}$	I	Power source for PWM or DAC playing output.
V <sub>DDA</sub> (7)	I	Power source. (For w536090/120T only)
$V_{DD}$	I	Power source.

- (4). RD1~3 are shared as CLK/DATA/ADDR to interface with W55XXX @W536030T/060T
- (5). @W536120T only
- (6). 0.1uF is default value, and capacitor value should be larger than 0.1uF if LCD dot size over 0.5mm\*0.5mm.
- (7). External application circuit should connect together, please refer to APPLICATION CIRCUIT. To sure chip operation properly, please bond all  $V_{DDP}$ ,  $V_{DDA}$ ,  $V_{DDD}$ ,  $V_{SSP}$ ,  $V_{SS}$  and  $V_{SSA}$  pads and connect  $V_{SSP}$ ,  $V_{SS}$  from chip outside PCB circuit.  $V_{SSA}$  and  $V_{DDA}$  are for W536090/120T only
- (8). When working at NMOS open drain mode, external pull high voltage can't higher than  $V_{DD}$  to avoid leakage current.



### 5. ELECTRICAL CHARACTERISTICS

## 5.1 Absolute Maximum Ratings

PARAMETER	RATING	UNIT
Supply Voltage to Ground Potential	-0.3 to +7.0	V
Applied Input/Output Voltage	-0.3 to +7.0	V
Power Dissipation	120	mW
Ambient Operating Temperature	0 to +70	°C
Storage Temperature	-55 to +150	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.

### 5.2 DC Characteristics

 $(V_{DD}-V_{SS}=3.0V, No load, FM=4 MHz with Ring mode, Fs=32.768 KHz, with Xtal mode, T_A=25° C, STN LCD panel on with dot size 0.5mm*0.5mm; unless otherwise specified)$ 

PARAMETER	SYM.	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Op. Voltage	VDD		2.4		5.5	V
Op. Current	lop1	Dual clock with crystal	-	600	700	μА
(No Load, no Voice,		Dual clock with Ring type		600	700	
No Melody)		Sub-clock only, LCD off		40	50	
		Sub-clock only, LCD on		70	90	
Hold Mode Current	lone	Cub aloak active only		6	10	
(No Load, LCD OFF)	IOP2	Sub-clock active only		0	10	μΑ
Hold Mode Current	IOP3	Sub-clock active only			70	^
(No load, LCD ON)	1023	Sub-clock active only			70	μΑ
Stop Mode Current	IOP4	LCD auto off			1	μА
CLK/ADDR Output High Current	Іон1	Vout = 2.7V			-0.8	mA
CLK/ADDR Output low Current	lo <sub>L</sub> 1	Vout = 0.4V			0.8	mA
Input Low Voltage	VIL	-	$V_{SS}$	-	0.3	$V_{DD}$
Input High Voltage	VIH	-	0.7	-	1	$V_{DD}$
Port RA, RB, RE, RF Output Low Voltage	VABL	I <sub>OL</sub> = 2.0 mA	_	-	0.4	V
Port RA, RB, RE, RF Output High Voltage	VABH	I <sub>OH</sub> = -2.0 mA	2.4	-	-	V

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### DC Characteristics, continued

PARAMETER	SYM.	CONDITIONS	MIN	TYP	MAX	UNIT
Pull-up Resistor	Rcd	Port RC, RD	200	300	400	ΚΩ
Share Output RI, RJ, RL, RN, RP Sink Current	lo <sub>L</sub> 3	VoL = 0.4V	-300			uA
RES Pull-up Resistor	RRES	-	50	100	200	ΚΩ
PWM1/2 Source Current (9)	ISPH	Volume Option = 00		-20		mA
$(R_{LOAD} = 8\Omega \text{ between PWM1}$		Volume Option = 01		-70		
And PWM2)		Volume Option = 10		-110		
		Volume Option = 11	.0	-135		
PWM1/2 Sink Current (9)	ISPL	Volume Option = 00	五万	20		mA
$(R_{LOAD} = 8\Omega \text{ between PWM1}$		Volume Option = 01	CX	70		
And PWM2)		Volume Option = 10	12	110		
		Volume Option = 11		135		
DAC output Current	IDAC	$V_{DD}$ = 3v, RL=100ohm	-4	-5	-6	mA
LCD Supply Current	ILCD	No Load, All Seg. ON	-	50	-	μΑ
COM/SEG On Resistor	Ron	$I_{OH} = \pm 50 \mu A$		5K	10K	Ω
V2 Pad Output Voltage	V <sub>RR</sub>	Depended on LCDM4	0.7		1.45	V
V2 Pad Output Deviation (10)	V <sub>D1</sub>	No Load			±5	%
V2 Pad Voltage Step	V <sub>R2</sub>	LCDM4 increased 1		50		mV
V6 Pad Output Voltage	\/ı op	4/4 Dies 9 malesd	3.8	3.85	3.9	V
(LCD's VLCD depended on	VLCD	1/4 Bias & no load	* V2	* V2	* V2	V
LCDM4 register) (10)		1/5 Bias & no load	4.75	4.8	4.85	
LODIVIA TEGISTEL) (10)		טמט אוט וטמט אוט פוט פו	* V2	* V2	* V2	
V2 Input Voltage	VEXT	LCDM3.3 = 1			1.5	V

<sup>(9)</sup> PWM current deviation will be  $\pm 20\%$ .

<sup>(10)</sup> VLCD deviation is governed by LCD dot size. More larger LCD dot will get larger deviation.



### 5.3 AC Characteristics

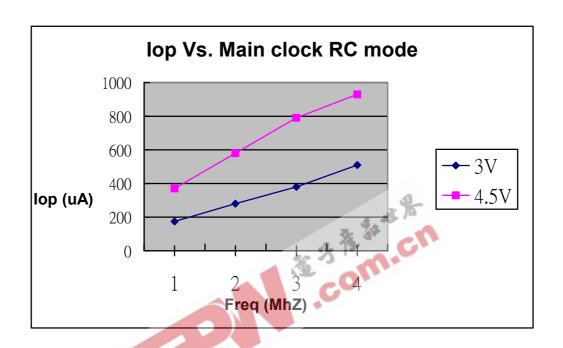
 $(V_{DD}-V_{SS}=3.0V, No load, FM=4 MHz with Ring mode, Fs=32.768 KHz, with Xtal mode, T_A=25^{\circ} C, STN LCD on with dot size 0.5mm*0.5mm; unless otherwise specified)$ 

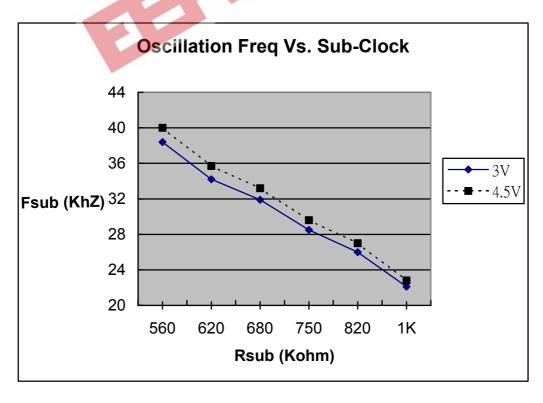
PARAMETER	SYM.	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Sub-clock Frequency	Fsub	Crystal type and X32IN and X32O with 17pF external cap.		32768		Hz
Main-clock Frequency	Fм	Ring type/Crystal type	400K	-	4M	Hz
Chip Operation Frequency	Fosc	SCR0.0 = 1, Fsys = Fsub		32768		Hz
		SCR0.0 = 0; Fsys = Fmain	400K	-	4M	
Instruction Cycle Time	Tcyc	One machine cycle	4	4/Fosc	-	S
Reset Active Width	TRAW	FOSC = 32.768 KHz	连作	-	-	μS
Interrupt Active Width	TIAW	FOSC = 32.768 KHz	1	_	-	μS
Main clock Ring frequency	FRXIN	RXIN = 680KΩ		1M		Hz
(11)		RXIN = 330K Ω		2M		
		RXIN = 200KΩ		ЗМ		
		RXIN = 130KΩ		4M		
Sub-Clock RC Oscillator	FRSUB	Rsu <b>B</b> = <b>680K</b> Ω		32		KHz
Sub-Clock Oscillation Stable Time @ Cold Start	FSTOP	RsuB = 680KΩ	0.8		1	S
Frequency Deviation of main-clock FRXIN ≤ 2MHz	<u>Δf</u> f	$\frac{f(3V) - f(2.4V)}{f(3V)}$			10	%
Frequency Deviation of main-clock FRXIN = 3MHz	<u>∆f</u> f	$\frac{f(3V) - f(2.4V)}{f(3V)}$			15	%
Frequency Deviation of main-clock FRXIN = 4 MHz	<u>∆f</u> f	$\frac{f(3V) - f(2.4V)}{f(3V)}$			20	%
ROSC Frequency	Frosc	Rosc = 680KΩ		3		MHz
Frequency Deviation of FROSC = 3MHz	<u>∆f</u> f	$\frac{f(3V) - f(2.4V)}{f(3V)}$			7.5	%
Frame frequency	FLCD	LCDM1 = 0111 b (default)		64		Hz

Notes:

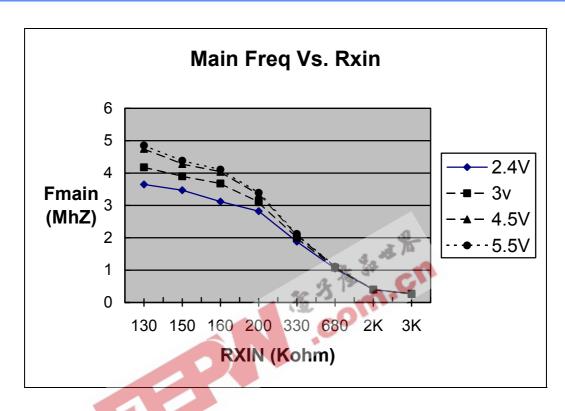
(11). The deviation will be +20% while VDD drops from 5.5V to 2.4V based on same resistor

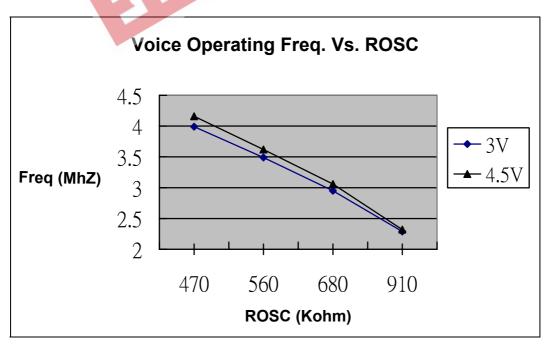










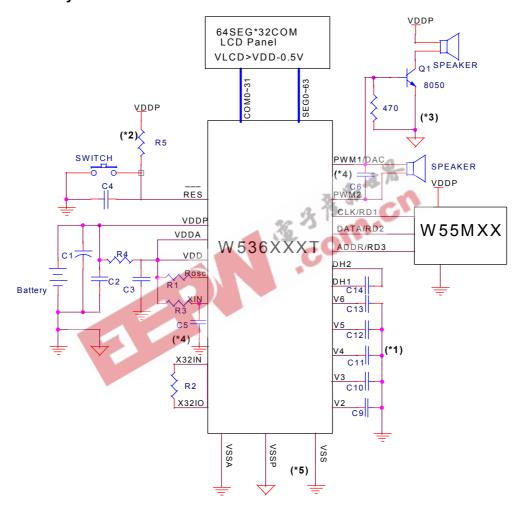




### 6. TYPICAL APPLICATION CIRCUITS

### 6.1 Sub Clock with RC Mode

#### 1/5 Bias 1/32 Duty



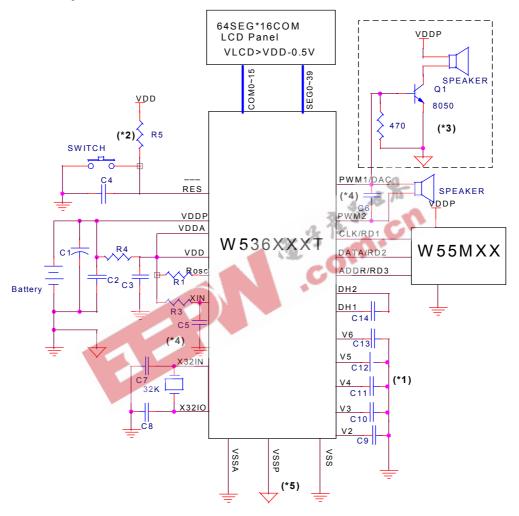
COMPONENT	C1	C2~C4	C5~C6	C7~C8	C9~C14	R1	R2	R3	R4
Value	4.7uF	0.1uF	100pF	-	0.1~1uF	680ΚΩ	680ΚΩ	650KΩ/1MHz 350KΩ/2MHz 225KΩ/3MHz 160KΩ/4MHz	100Ω

- 1. C9~C14 depends on LCD panel dot size.
- 2. Option R5 equals to  $100\Omega$  if high noise immunity is needed.
- 3. For DAC option application.
- 4. To ensure that three batteries function well in W536F20 demo board.  $C_6$  should stay close to pad PWM/PWM2 at its best. Under the mask ROM version,  $C_5$  and  $C_6$  can be skipped.
- 5. Sure chip operation properly, please bond all  $V_{DDP}$ ,  $V_{DD}$ ,  $V_{DDA}$ ,  $V_{SSP}$ , and  $V_{SSP}$  and  $V_{SSP}$  and connect  $V_{SSP}$  pad to  $V_{SS}$  from external PCB circuit.  $V_{SSA}$  and VDDA are for W536090T/120T only.



## 6.2 Sub Clock with Crystal Mode

### 1/5 Bias 1/16 Duty



COMPONENT	C1	C2~C4	C5~C6	C7~C8	C9~C14	R1	R2	R3	R4
Value	4.7uF	0.1uF	100pF	15-30PF	0.1~1uF	680ΚΩ	-	650KΩ/1MHz 350KΩ/2MHz 225KΩ/3MHz 160KΩ/4MHz	100Ω

- 1. C9~C14 depends on LCD panel dot size.
- 2. Option R5 equals to  $100\Omega$  if high noise immunity is needed.
- 3. For DAC option application.
- 4. To ensure that three batteries function well in W536F20 demo board.  $C_6$  should stay close to pad PWM/PWM2 at its best. Under the mask ROM version,  $C_5$  and  $C_6$  can be skipped.
- 5. Sure chip operation properly, please bond all  $V_{DDP}$ ,  $V_{DD}$ ,  $V_{DDA}$ ,  $V_{SSA}$ ,  $V_{SSP}$  and  $V_{SS}$ ; and connect  $V_{SSP}$  pad to  $V_{SS}$  from external PCB circuit.  $V_{SSA}$  and  $V_{DDA}$  are for W536090T/120T only.



#### 7. REVISION HISTORY

VERSION	DATE	WRITER	DESCRIPTION						
A2	Aug. 10, 1999	YCHuang	MASK option						
A3	Aug. 23,1999	Judy Kuo	W536060A to 12io only, and external speech shared RD port except W536120X Part No						
A4	April 13, 2000	Judy Kuo	Modify some errors and add "Tri-state serial bus" mask option and cascaded voice ROM function						
A5	Sep. 10, 2000	Jimmy Chen	Add Application Circuit						
A6	Dec. 15, 2000	Jimmy Chen	Add AC Picture						
A7	May 22, 2001	Jimmy Chen	Application circuit modify						
A8	May 21, 2003	Jimmy Chen	<ul><li>Application circuit modify</li><li>Melody Function</li></ul>						
• Nelogy-Function									



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